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Strain engineering of MoS_2/graphene heterostructrures by thermal treatment

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Two-dimensional (2D) transition metal dichalcogenides (TMDCs) and graphene constitute a new class of atomically thin materials that possess exotic mechanical, electrical and optical properties [1]. Thanks to their characteristic exceptional mechanical strength and flexibility, 2D materials provide an ideal platform for strain engineering, enabling tunable modulation and significant improvement of their optical properties [2]. With the application of external fields such as uniaxial or biaxial strain, one can demonstrate flexible control over their electronic states. Meanwhile, many nondestructive spectroscopic and microscopic characterization tools can be readily harnessed to quantitatively determine strain-engineered alterations in these properties. Furthermore, transferring 2D materials onto pre-patterned substrates provides a means of introducing inhomogeneous and guided local strains into any type of 2D material, which is of great technological interest [3].

In the work presented here, molybdenum disulfide (MoS_2) was directly exfoliated on top of transferred CVD graphene, which enabled directed strain distributions hailing from the wrinkled graphene topography. Additionally, another degree of strain was introduced and controlled by a simple thermal treatment owing to the thermal expansion of the substrate, which also affected the interlayer bonding of the heterostructures. The variations in the resulting optical and electrical properties were assessed with Raman spectroscopy, Photoluminescence and Kelvin Probe Force Microscopy, and displayed effective control in temperatures as low as 125 °C for the aforementioned properties. The prospect of these findings can pave the way for low-cost and controllable engineering of devices directly on insulating substrates.

References

[1] K. S. Novoselov *et al., PNAS,* 102 (30) 10451-10453 (2005)

[2] R. Roldán *et al., J. Phys.: Condens. Matter,* 27 313201 (2015)

[3] Y. Han et al., *Appl Nanosci* 11 1075–1091 (2021)

Figures

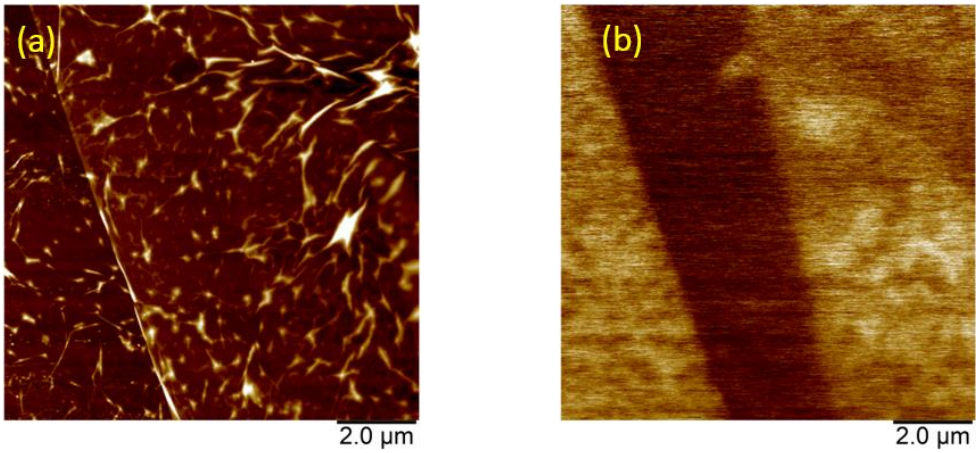

Figure 1: (a) Topography and (b) surface potential of MoS_2/graphene heterostructure